

Data sheet acquired from Harris Semiconductor SCHS211D

November 1997 - Revised October 2003

High-Speed CMOS Logic 8-Stage Shift and Store Bus Register, Three-State

Features

- · Buffered Inputs
- Separate Serial Outputs Synchronous to Both Positive and Negative Clock Edges For Cascading
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_I \le 1\mu A$ at V_{OL} , V_{OH}

Description

The 'HC4094 and CD74HCT4094 are 8-stage serial shift registers having a storage latch associated with each stage for strobing data from the serial input to parallel buffered three-state outputs. The parallel outputs may be connected directly to common bus lines. Data is shifted on positive clock transitions. The data in each shift register stage is transferred to the storage register when the Strobe input is high. Data in the storage register appears at the outputs whenever the Output-Enable signal is high.

Two serial outputs are available for cascading a number of these devices. Data is available at the QS_1 serial output terminal on positive clock edges to allow for high-speed operation in cascaded system in which the clock rise time is fast. The same serial information, available at the QS_2 terminal on the next negative clock edge, provides a means for cascading these devices when the clock rise time is slow.

Ordering Information

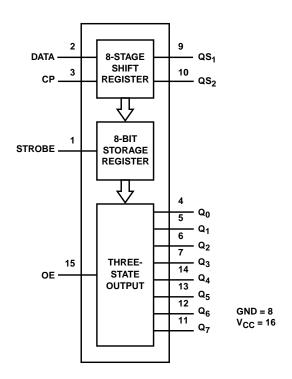
PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC4094F3A	-55 to 125	16 Ld CERDIP
CD74HC4094E	-55 to 125	16 Ld PDIP
CD74HC4094M	-55 to 125	16 Ld SOIC
CD74HC4094MT	-55 to 125	16 Ld SOIC
CD74HC4094M96	-55 to 125	16 Ld SOIC
CD74HC4094NSR	-55 to 125	16 Ld SOP
CD74HC4094PW	-55 to 125	16 Ld TSSOP
CD74HC4094PWR	-55 to 125	16 Ld TSSOP
CD74HC4094PWT	-55 to 125	16 Ld TSSOP
CD74HCT4094E	-55 to 125	16 Ld PDIP
CD74HCT4094M	-55 to 125	16 Ld SOIC
CD74HCT4094MT	-55 to 125	16 Ld SOIC
CD74HCT4094M96	-55 to 125	16 Ld SOIC

NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel. The suffix T denotes a small-quantity reel of 250.

Pinout

CD54HC4094 (CERDIP)
CD74HC4094 (PDIP, SOIC, SOP, TSSOP)
CD74HCT4094 (PDIP, SOIC)
TOP VIEW

Functional Diagram



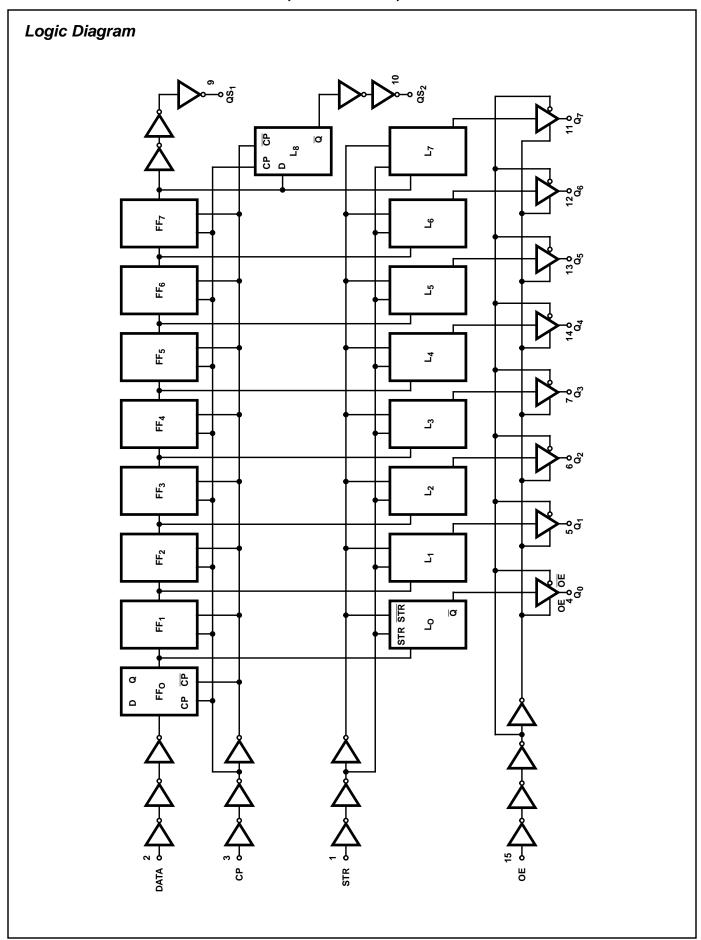
TRUTH TABLE

	INPL	JTS		PARALLEL	OUTPUTS	SERIAL OUTPUTS		
СР	OE	STR	D	Q_0	Q _n	QS ₁ (NOTE 1)	QS ₂	
1	L	Х	Х	Z	Z	Q'6	NC	
\	L	Х	Х	Z	Z	NC	Q ₇	
1	Н	L	Х	NC	NC	Q'6	NC	
1	Н	Н	L	L	Q _n -1	Q'6	NC	
1	Н	Н	Н	Н	Q _n -1	Q'6	NC	
\	Н	Н	Н	NC	NC	NC	Q ₇	

 $H = High \ Voltage \ Level, \ L = Low \ Voltage \ Level, \ X = Don't \ Care, \ NC = No \ charge, \ Z = High \ Impedance \ Off-state,$

 $[\]uparrow$ = Transition from Low to High Level, \downarrow = Transition from High to Low.

^{1.} At the positive clock edge the information in the seventh register stage is transferred to the 8th register stage and QS1 output.



Absolute Maximum Ratings

DC Supply Voltage, V _{CC}	0.5V to 7V
DC Input Diode Current, I _{IK}	
For $V_1 < -0.5V$ or $V_1 > V_{CC} + 0.5V$	±20mA
DC Output Diode Current, I _{OK}	
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$	±20mA
DC Output Source or Sink Current per Output Pin, IO	
For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$	±25mA
DC V _{CC} or Ground Current, I _{CC}	±50mA

Thermal Information

Package Thermal Impedance, θ _{JA} (see Note 2):
E (PDIP) Package
M (SOIC) Package73°C/M
NS (SOP) Package
PW (TSSOP) Package108 ^o C/W
Maximum Junction Temperature (Plastic Package) 150 ⁶
Maximum Storage Temperature Range65°C to 150°
Maximum Lead Temperature (Soldering 10s)
SOIC - Lead Tips Only)

Operating Conditions

Temperature Range (T _A)	55°C to 125°C
Supply Voltage Range, V _{CC}	
HC Types	2V to 6V
HCT Types	4.5V to 5.5V
DC Input or Output Voltage, V _I , V _O	0V to V _{CC}
Input Rise and Fall Time	
2V	1000ns (Max)
4.5V	500ns (Max)
6V	400ns (Max)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

2. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

	c		TEST CONDITIONS		25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input V _{IH} Voltage	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
				4.5	3.15	-	-	3.15	-	3.15	-	V
			6	4.2	-	-	4.2	-	4.2	-	V	
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V _{OH}	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
omeo Loudo			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	7		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
112 20000			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
OWIGO Educa			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output	7		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
TTL LOAUS			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lį	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μΑ

DC Electrical Specifications (Continued)

		TES CONDI		V _{CC}	25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES					-	-	-	-	-	-	-	
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	Voн	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	ΙĮ	V _{CC} and GND	0	5.5	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	lcc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μΑ
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 3)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ

NOTE:

HCT Input Loading Table

INPUT	UNIT LOADS						
D	0.4						
CP, OE	1.5						
STR	1.0						

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Table, e.g., 360µA max at 25 $^{\rm o}C.$

Prerequisite for Switching Specifications

		V _{CC} (V)	25	°C	-40°C T	O 85°C	-55°C TO 125°C		
CHARACTERISTIC	SYMBOL		MIN	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES			•						
CP Pulse Width	t _W	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
STR Pulse Width	t _{WH}	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns

^{3.} For dual-supply systems theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.

Prerequisite for Switching Specifications (Continued)

			25°C		-40°C 1	ГО 85 ⁰ С	-55°C T		
CHARACTERISTIC	SYMBOL	V _{CC} (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
Data Set-up Time	t _{SU}	2	50	-	65	-	75	-	ns
		4.5	10	-	13	-	15	-	ns
		6	9	-	11	-	13	-	ns
Data Hold Time	tH	2	3	-	3	-	3	-	ns
		4.5	3	-	3	-	3	-	ns
		6	3	-	3	-	3	-	ns
STR Set-up Time	tsu	2	100	-	125	-	150	-	ns
		4.5	20	-	25	-	30	-	ns
		6	17	-	21	-	26	-	ns
STR Hold Time	t _H	2	0	-	0	-	0	-	ns
		4.5	0	-	0	-	0	-	ns
		6	0	-	0	-	0	-	ns
Maximum CP Frequency	fCL (MAX)	2	6	-	5	-	4	-	MHz
		4.5	30	-	24	-	20	-	MHz
		6	35	-	28	-	24	-	MHz
HCT TYPES			-			-	-	-	
CP Pulse Width	t _W	4.5	16	-	20	-	24	-	ns
STR Pulse Width	t _{WH}	4.5	16	-	20	-	24	-	ns
Data Set-up Time	t _{SU}	4.5	10	-	13	-	15	-	ns
Data Hold Time	t _H	4.5	4	-	4	-	4	-	ns
STR Set-up Time	tsu	4.5	20	-	25	-	30	-	ns
STR Hold Time	t _H	4.5	0	-	0	-	0	-	ns
Maximum CP Frequency	f _{CL} (MAX)	4.5	30	-	24	-	20	-	MHz

Switching Specifications Input $t_{\text{r}}, \, t_{\text{f}} = 6 \text{ns}$

		TEST CONDITIONS	V _{CC}		25°C		-40°C T	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL			MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES											
Propagation Delay Time (Figure 1)	t _{PLH,} t _{PHL}	C _L = 50pF	2	-	-	150	-	190	-	225	ns
CP to QS ₁			4.5	-	-	30	-	38	-	45	ns
		C _L =15pF	5	-	12	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	26	-	33	-	38	ns
CP to QS ₂	t _{PLH} ,	C _L = 50pF	2	-	-	135	-	170	-	205	ns
	t _{PHL}		4.5	-	-	27	-	34	-	41	ns
		C _L =15pF	5	-	11	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	23	-	29	-	35	ns
CP to Q _n	t _{PLH} ,	C _L = 50pF	2	-	-	195	-	245	-	295	ns
	t _{PHL}		4.5	-	-	39	-	49	-	59	ns
			5	-	16	-	-	-	-	-	ns
			6	-	-	33	-	42	-	50	ns
STR to Q _n	t _{PLH} ,	C _L = 50pF	2	-	-	180	-	225	-	270	ns
	t _{PHL}		4.5	-	-	36	-	45	-	54	ns
		6	-	-	31	-	38	-	46	ns	

Switching Specifications Input $t_{\text{r}}, \, t_{\text{f}} = 6 \text{ns}$ (Continued)

		TEST CONDITIONS	v _{cc}		25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL		(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Output Enable to Q _n	t _{PZH} , t _{PZL}	C _L = 50pF	2	-	-	175	-	220	-	265	ns
			4.5	-	-	35	ı	44	ı	53	ns
			6	-	-	30	ı	37	ı	45	ns
Output Disable to Q _n	t _{PHZ} , t _{PLZ}	C _L = 50pF	2	-	-	125	ı	155	ı	190	ns
			4.5	-	-	25	ı	31	ı	38	ns
			6	-	-	21	-	26	-	32	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Output Disabling Time	t _{PHZ} , t _{PLZ}	C _L =15pF	5	-	10	-	-	-	-	-	ns
Maximum CP Frequency	f _{MAX}	C _L =15pF	5	-	60	-	-	-	-	-	MHz
Input Capacitance	C _{IN}	C _L = 50pF	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	C _L =15pF	5	-	90	-	-	-	-	-	pF
Three-State Output Capacitance	c _o	C _L = 50pF	-	-	-	15	-	15	-	15	pF
HCT TYPES											
Propagation Delay Time (Figure 1)	t _{PLH,} t _{PHL}	C _L = 50pF	4.5	-	-	39	-	-	-	-	ns
CP to QS ₁		C _L =15pF	5	-	16	-	-	-	-	-	ns
CP to QS ₂	t _{PLH,}	C _L = 50pF	4.5	-	-	36	-	-	-	-	ns
	tPHL	C _L =15pF	5	-	15	-	-	-	-	-	ns
CP to Q _n	t _{PLH,}	C _L = 50pF	4.5	-	-	43	-	-	-	-	ns
	tPHL	C _L =15pF	5	-	18	-	-	-	-	-	ns
STR to Q _n	t _{PLH,} t _{PHL}	C _L = 50pF	4.5	-	-	39	-	-	-	-	ns
Output Enable to Q _n	t _{PZH} , t _{PZL}	C _L = 50pF	4.5	-	-	35	-	-	-	-	ns
Output Disable to Q _n	t _{PHZ} , t _{PLZ}	C _L = 50pF	4.5	-	-	35	-	-	-	-	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	15	-	-	-	-	ns
Output Disabling Time	t _{PHZ} , t _{PLZ}	C _L =15pF	5	-	14	-	-	-	-	-	ns
Maximum CP Frequency	f _{MAX}	C _L =15pF	5	-	60	-	-	-	-	-	MHz
Input Capacitance	C _{IN}	C _L = 50pF	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	C _L =15pF	5	-	110	-	-	-	-	-	pF
Three-State Output Capacitance	C _O	C _L = 50pF	-	-	-	15	-	15	-	15	pF

 ^{4.} C_{PD} is used to determine the dynamic power consumption, per register.
 5. P_D = V_{CC}² f_i (C_{PD} + C_L) where f_i = Input Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms

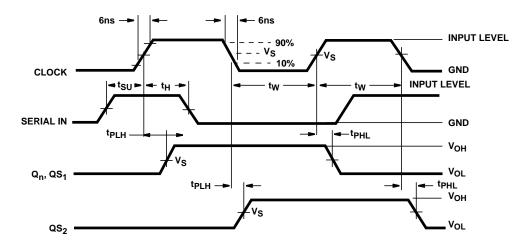


FIGURE 1. DATA PROPAGATION DELAYS, SET-UP AND HOLD TIMES

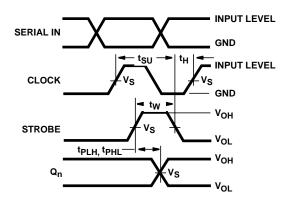


FIGURE 2. STROBE PROPAGATION DELAYS AND SET-UP AND HOLD TIMES

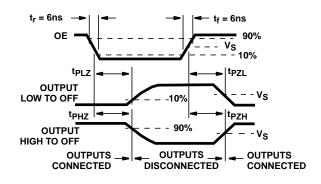


FIGURE 3. ENABLE AND DISABLE TIMES







PACKAGING INFORMATION

	Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	n MSL Peak Temp ⁽³⁾
	CD54HC4094F3A	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
	CD74HC4094E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
	CD74HC4094M	ACTIVE	SOIC	D	16	40	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
Ī	CD74HC4094M96	ACTIVE	SOIC	D	16	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
	CD74HC4094M96E4	ACTIVE	SOIC	D	16	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
	CD74HC4094ME4	ACTIVE	SOIC	D	16	40	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
	CD74HC4094MT	ACTIVE	SOIC	D	16	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
	CD74HC4094MTE4	ACTIVE	SOIC	D	16	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
	CD74HC4094NSR	ACTIVE	SO	NS	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
	CD74HC4094NSRE4	ACTIVE	SO	NS	16	2000	TBD	Call TI	Call TI
	CD74HC4094PW	ACTIVE	TSSOP	PW	16	90	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
	CD74HC4094PWE4	ACTIVE	TSSOP	PW	16	90	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
	CD74HC4094PWR	ACTIVE	TSSOP	PW	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
	CD74HC4094PWRE4	ACTIVE	TSSOP	PW	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
	CD74HC4094PWT	ACTIVE	TSSOP	PW	16	250	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
	CD74HC4094PWTE4	ACTIVE	TSSOP	PW	16	250	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
	CD74HCT4094E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
	CD74HCT4094M	ACTIVE	SOIC	D	16	40	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
	CD74HCT4094M96	ACTIVE	SOIC	D	16	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
Ī	CD74HCT4094M96E4	ACTIVE	SOIC	D	16	2500	TBD	Call TI	Call TI
Ī	CD74HCT4094ME4	ACTIVE	SOIC	D	16	40	TBD	Call TI	Call TI
	CD74HCT4094MT	ACTIVE	SOIC	D	16	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
Ī	CD74HCT4094MTE4	ACTIVE	SOIC	D	16	250	TBD	Call TI	Call TI
_									

(1) The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



PACKAGE OPTION ADDENDUM

27-May-2005

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AC.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DSP	dsp.ti.com	Broadband	www.ti.com/broadband
Interface	interface.ti.com	Digital Control	www.ti.com/digitalcontrol
Logic	logic.ti.com	Military	www.ti.com/military
Power Mgmt	power.ti.com	Optical Networking	www.ti.com/opticalnetwork
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
		Telephony	www.ti.com/telephony
		Video & Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments

Post Office Box 655303 Dallas, Texas 75265

Copyright © 2005, Texas Instruments Incorporated